



**Thunder High Power Products** 

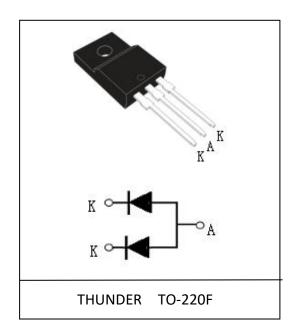
**THR10U06RF** 

# FRD Ultrafast Soft Recovery Diode,10A

#### Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction

Product Summary	
VR	600 V
lf(AV)	2*5A
trr	21ns



# **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

# Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	10	
Single pulse forward current	Ifsm	Tc =25°C	100	A
Maximum repetitive forward current	Ifrm	Square wave, 20kHZ	40	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C





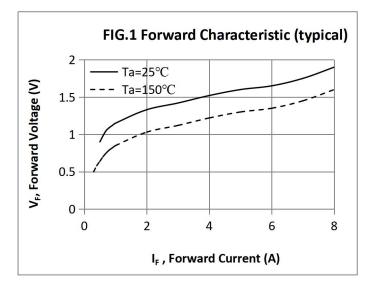
# Electrical characteristics (Ta=25°C unless otherwise specified)

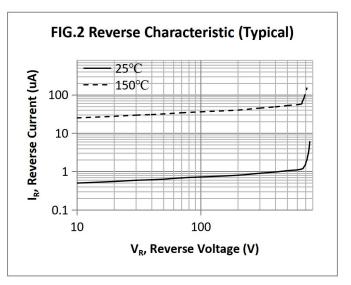
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage	Vbr,		600			
Blocking voltage	V <sub>R</sub>	Ir=100µA	800			
Forward voltage (Per Diode)		IF=5A		1.30	1.50	V
	VF	I⊧=5A, Tj =125°C		1.20	1.40	
Reverse leakage current(Per Diode)		Vr= Vrrm			2	
	Tj=150°C, Vr=600V			30	μΑ	
Reverse recovery time(Per Diode)	+	I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		30	50	nc
	Lrr	I <sub>F</sub> =1A,V <sub>R</sub> =30V, di/ <i>dt</i> =200A/us		21	35	ns

# **Thermal characteristics**

Paramter	Symbol	Тур	Units
R <sub>θJC</sub>	Junction-to-Case	2.5	°C/W

# **Electrical performance (typical)**

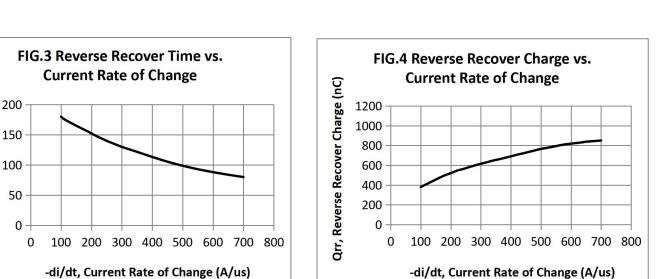


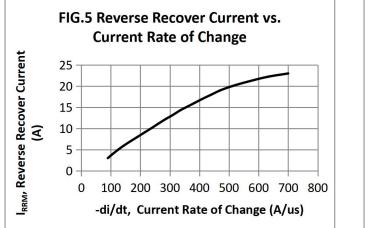


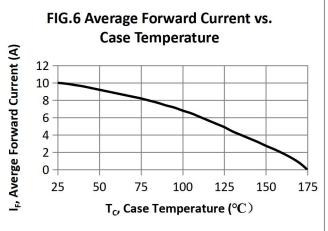


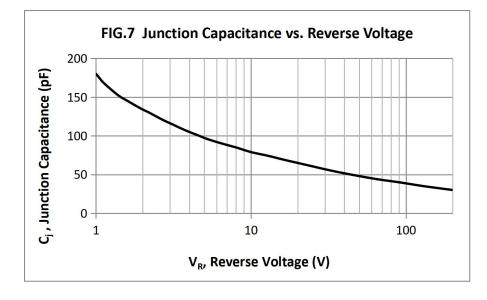
Trr, Reverse Recover Time (ns)

THR10U06RF





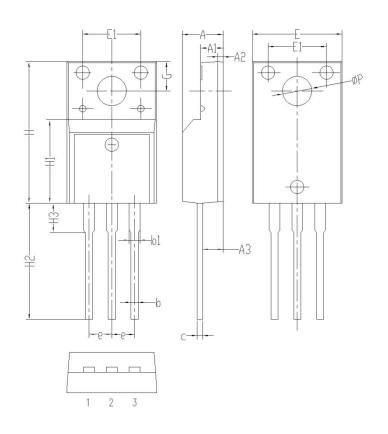








# **Package Information**



#### 单位 mm Symbol Min Nom Max 4.55 4.75 4.95 А 2.40 2.60 2.80 A1 0.40 A2 0.60 0.80 0.80 b 0.60 1.00 0.42 0.50 0.58 с 2.30 2.50 2.70 e Е 9.9 10.1 10.3 E1 0.68 0.70 0.72 Н 15.8 16.0 16.2 Η1 9.10 9.30 9.50 12.9 13.2 13.5 H2 3.10 3.30 H3 3.50 G 3.10 3.30 3.50

3.00

3.20

3.40

ΦР

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**TO-220F PACKAGE** 

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-Headquarters					
WuXi Thunder Microelectro	nics Incorporated Limited				
Building E1-9F, No.200 LingHu Road, XinWu district,WuXi,China 214135					
Tel:+86-510-85160109	Fax:+86-510-85160109				